



HARRIS

勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-34970699
 勝特力电子(深圳) 86-755-83298787
 Http://www.100y.com.tw

HI-508L/HI-509L

**Single 8/Differential 4 Channel
 CMOS Analog Multiplexers With
 Latches And Overvoltage Protection**

FEATURES

- Analog Overvoltage protection
- Resettable Latches (RS)
- TTL/DTL and CMOS Compatible
- Failsafe for conditions of Overvoltage & Loss of Power
- No SCR Latch-up
- Break-before-make switching
- Microprocessor Bus compatible
- Very low leakage - $I_{D(off)} \leq 4\text{nA}$ (typ) over full temp range
- Access time - $t_A = 500\text{nS}$ (typ)
- Minimum write pulse width (WR) = 300 nS
- OFF isolation = -100dB, typ @ 10kHz

DESCRIPTION

These monolithic CMOS multiplexers feature on-board address latches, plus overvoltage protection for the analog inputs and the output as well. Each model includes digital inputs for channel selection and an Enable input for device selection under program control. In addition, Write (WR) and Reset (RS) inputs allow the program to store or clear the channel address.

The overvoltage performance of these multiplexers is particularly useful in redundant systems, where the inputs and output must present a high impedance when power is off. This is achieved by a switch cell with three MOSFET's in series, rather than the conventional transmission gate design.

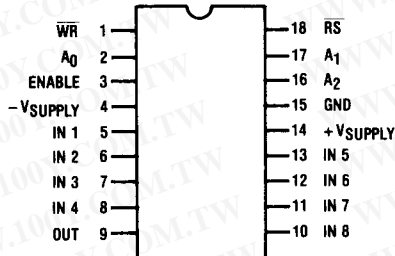
Each channel can withstand overvoltage to +25VDC with respect to ground with power ON or OFF. An OFF channel remains OFF in the presence of overvoltage. If the channel is ON, output voltage is clamped below the supply rail, which protects the load circuit.

The HI-508L offers 8 single-ended channels, and the HI-509L is a 4 channel differential version. The recommended supply voltages are 15V, though operation at reduced levels or with a single supply may also be implemented. The package is a 18 pin ceramic or plastic DIP.

Each product is specified for the commercial temperature range (0°C to 75°C, -5 suffix) and the military range (-55°C to +125°C, -2 suffix). Military high reliability burned-in product is available as a "-8" suffix.

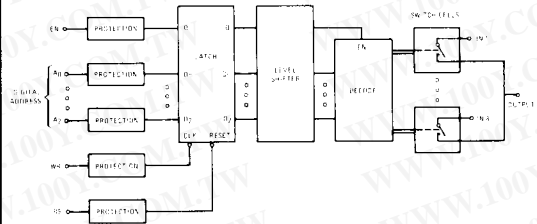
PINOUT

HI-508L

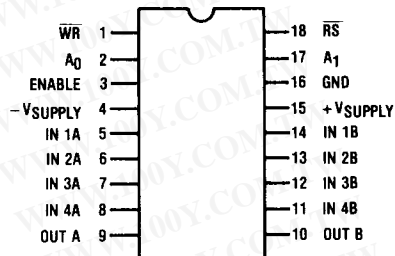


FUNCTIONAL DIAGRAM

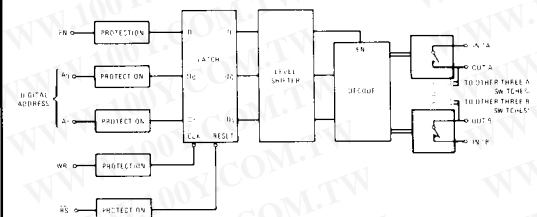
HI-508L



HI-509L



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CAUTION: Electronic devices are sensitive to electrostatic discharge. Proper I.C. handling procedures should be followed.

SPECIFICATIONS

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HI-508L/509L

ABSOLUTE MAXIMUM RATINGS (Note 1)

Supply Voltage Between Pins 4 and 14 (15)	44V	Operating Temperature	
Digital Input Overvoltage, V _A , V _{EN} , V _{RS} , V _{WR} :		HI-508L/509L-2	-55°C to 125°C
V supply (+)	+4V	HI-508L/509L-5	0°C to 75°C
V supply (-)	-4V	Storage Temperature	-65°C to +150°C
Analog Overvoltage			
Input to Ground	±25VDC		
Total Power Dissipation* (Package)	1200mW	*Derate-8mW/°C above T _A = +75°C	

ELECTRICAL CHARACTERISTICS

(Unless otherwise specified)

+V supply = 15V, -V supply = -15V, V_{AH} (Logic High) = 2.0V, V_{AL} (Logic Low) = 0.8V

PARAMETER	HI-508L/509L-2 -55°C to +125°C				HI-508L/509L-5 0°C to +75°C			UNITS
	TEMP	MIN	TYP	MAX	MIN	TYP	MAX	
ANALOG CHANNEL CHARACTERISTICS								
V _S Analog Signal Range	Full		±10			±10		V
R _{ON} , ON Resistance (Note 2)	+25°C			1.2			1.5	KΩ
	Full			1.8			1.8	KΩ
ΔR _{ON} , Change in R _{ON} (Note 3) between channels	+25°C		5			5		%
I _{S(off)} , OFF input leakage current	+25°C			10			10	nA
	Full		5	50		5	50	nA
I _{D(off)} , OFF output leakage current	+25°C			10			10	nA
	Full		4	100		4	100	nA
	HI-508L		2	50		2	50	nA
I _{D(on)} , ON Channel leakage current	+25°C			10			10	nA
	Full		5	100		5	100	nA
	HI-508L		2	50		2	50	nA
	HI-509L							
FAULT CHARACTERISTICS								
I _{S(off)} , with Power OFF	Full		10	1000		10	5000	nA
I _{S(off)} , overvoltage (Note 4)	Full		10	750		10	2500	nA
I _{D(off)} , with input over- voltage applied (Note 4)	+25°C		5			5		nA
	Full		10	750		10	2500	nA
DIGITAL INPUT CHARACTERISTICS								
V _{AL} , Input Low Threshold	Full		1.4	0.8		1.4	0.8	V
V _{AH} , Input High Threshold	Full	2.0	1.4		2.0	1.4		V
I _{AH} , Input High Current (Note 5)	Full		10	40		10	40	μA
I _{AL} , Input Low Current (Note 5)	Full		40	200		40	200	μA
DYNAMIC SWITCHING CHARACTERISTICS (Note 6)								
t _a , Access Time	+25°C		0.5	1.0		0.5	1.0	μS
t _{OPEN} , Break-Before-Make	+25°C	.025	0.1		.025	0.1		μS
t _{ON} , (EN), Enable Delay (ON)	+25°C		0.5	1.0		0.5	1.0	μS
t _{OFF} , (EN), Enable Delay (OFF)	+25°C		0.5	1.0		0.5	1.0	μS
Settling Time (±0.1%)	+25°C		1.0			1.0		μS
	+25°C		1.75			1.75		μS
OFF Isolation (Note 7)	+25°C	50	68		50	68		dB
OFF Isolation POWER OFF (Note 8)	+25°C		56			56		dB
C _{S(off)} , Channel Input Cap.	+25°C		5			5		pF
C _{D(off)} , Channel Output Cap.								
	+25°C		25			25		pF
	+25°C		12			12		pF
C _A , Digital Input Capacitance	+25°C		5			5		pF
C _{DS(off)} , Input to Output capacitance	+25°C		0.1			0.1		pF
POWER REQUIREMENTS								
P _d , Power Dissipation (Note 9)	Full		60	100		60	100	mW
I ₊ , Current Pin 14 (Note 9)	Full		3.7	6.0		3.7	6.0	mA
I ₋ , Current Pin 4 (Note 9)	Full		0.3	0.6		0.3	0.6	mA

NOTES 1 Absolute maximum ratings are limiting values applied individually, beyond which the serviceability of the circuit may be impaired. Functional operation under any of these conditions is not necessarily implied.
 2 V_{OUT} = ±10V, I_{OUT} = -100μA
 3 ΔR_{ON} = R_{ON}(Max) - R_{ON}(Min), V_{IN} = ±10V

$$\frac{R_{ON(Avg)}}{R_{ON(Min)}}$$

 4 Analog Overvoltage = ±25V

5 I_{AH} and I_{AL} tested at 2.4V and 0.4V respectively
 6 For measurements in this section, input logic levels are 3.0V (High) and 0V (Low)
 7 V_{CM} = 0.8V, R_L = 1KΩ, C_L = 15pF, V_S = 70ms, f = 500kHz
 Off Isolation = 20 log $\frac{|V_O|}{|V_S|}$
 Worst case isolation on channel 4 due to proximity of the output pin(s)

8 V₊, V₋ = 0V, R_L = 1KΩ
 C_L = 50pF, V_S = 3Vrms, f = 500 kHz
 9 See Test Circuit #8 for high toggle frequency applications

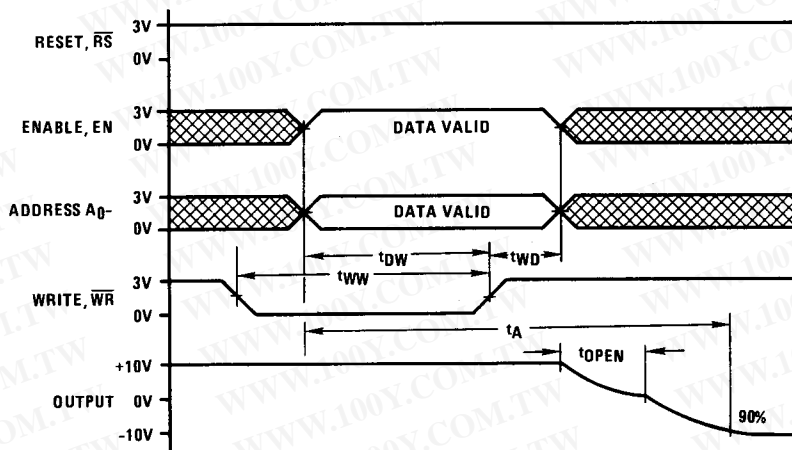
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MULTIPLEXERS

MINIMUM TIMING REQUIREMENTS

PARAMETER	MIN LIMITS FULL TEMP RANGE	UNITS
t_{WW} Write Pulse Width	300	nS
t_{DW} A. EN Data Valid To WRITE (Stabilization Time)	225	nS
t_{WD} A. EN Data Valid After Write (hold Time)	100	nS
t_{RS} RESET pulse width	400	nS
t_{OFF} (RS) Reset Delay	1000	nS
t_{ON} (WR) Write Turn-on Time	1000	nS

TIMING REQUIREMENTS



1. $+V_{SUPPLY} = +15V$; $-V_{SUPPLY} = -15V$.
2. Logic Levels: $V_{AL} = 0V$; $V_{AH} = +3.0V$.
3. Time intervals are measured between 50% levels unless otherwise noted.
4. Minimum values for t_{RS} , t_{DW} , t_{WW} and t_{WD} are guaranteed separately but not simultaneously.

Figure 1

SCHEMATIC DIAGRAM

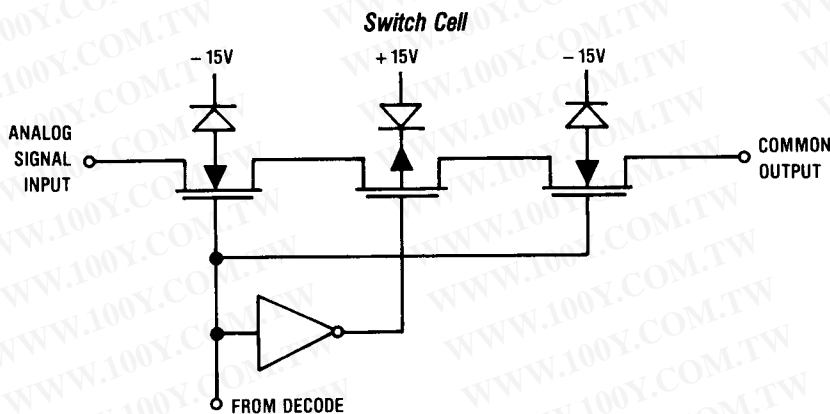


Figure 2

508L

A2	A1	A0	EN	WR	RS	OUTPUT - ON CHANNEL
X	X	X	L	L	H	None
X	X	X	X		H	Previous ON Channel.
X	X	X	X	X	L	None (latches cleared)
L	L	L	H	L	H	Channel 1
L	L	H	H	L	H	Channel 2
L	H	L	H	L	H	Channel 3
L	H	H	H	L	H	Channel 4
H	L	L	H	L	H	Channel 5
H	L	H	H	L	H	Channel 6
H	H	L	H	L	H	Channel 7
H	H	H	H	L	H	Channel 8

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MULTIPLEXERS

509L

A1	A0	EN	WR	RS	OUTPUT - ON CHANNEL PAIR
X	X	L	L	H	None
X	X	X		H	Previous ON Channel.
X	X	X	X	L	None (latches cleared)
L	L	H	L	H	Channel 1A and 1B
L	H	H	L	H	Channel 2A and 2B
H	L	H	L	H	Channel 3A and 3B
H	H	H	L	H	Channel 4A and 4B

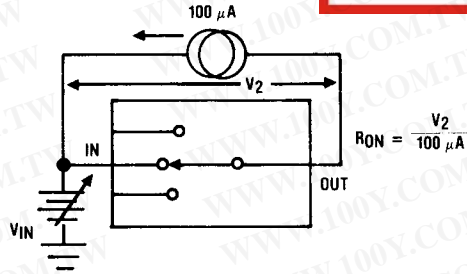
DESCRIPTION AND APPLICATION

The switch cell of HI-508L/509L has a different structure than earlier Harris designs (HI-508, HI508A). The new switch (Figure 2) consists of an N-channel, P-channel and N-channel MOSFET in series, as opposed to the transmission gate configuration with an N and P-channel device in parallel. The series N-P-N switch offers higher Off isolation with power off, and better fault performance. Channel overvoltage protection is inherent since one of the three MOSFETs turn off in the presence of overvoltage. This turn-off process begins well below the supply rail so the V_{IN} range is less than the power supply range. Electrical performance is guaranteed to $\pm 10V$ for each channel, and the usable range extends above ± 11 Volts.

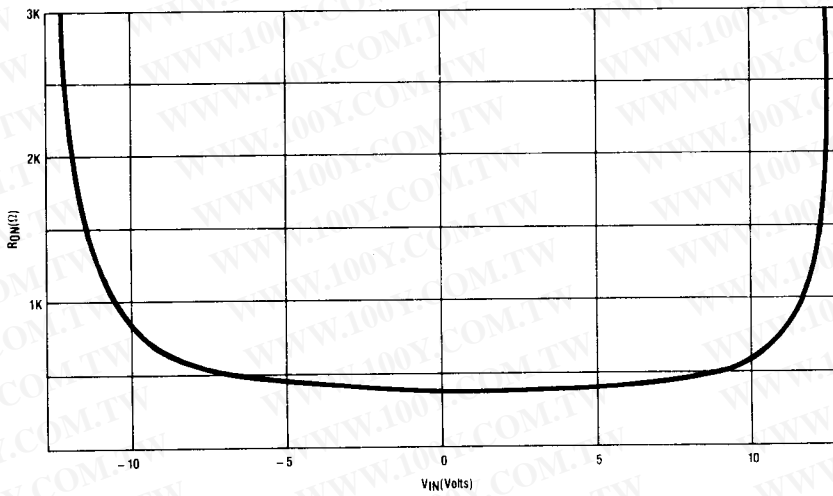
The address inputs A_0 , A_1 , A_2 , and ENABLE are latched into an internal buffer when WR goes high. Each latch output is level shifted into the decode section, which activates the appropriate channel. The device may be reset (all channels OFF) by taking RS low. Usually, RS is tied to the system RESET line, to assure that all channels are OFF following a turn-on of power. The reset function overrides all others, just as WR overrides the address inputs (A_0 - A_2 and EN are ignored when WR is high). With WR low and RS high, the switches respond immediately to a change in channel address; i.e., the latches are "transparent". Refer to Figure 1.

For additional Applications information please see AN 545.

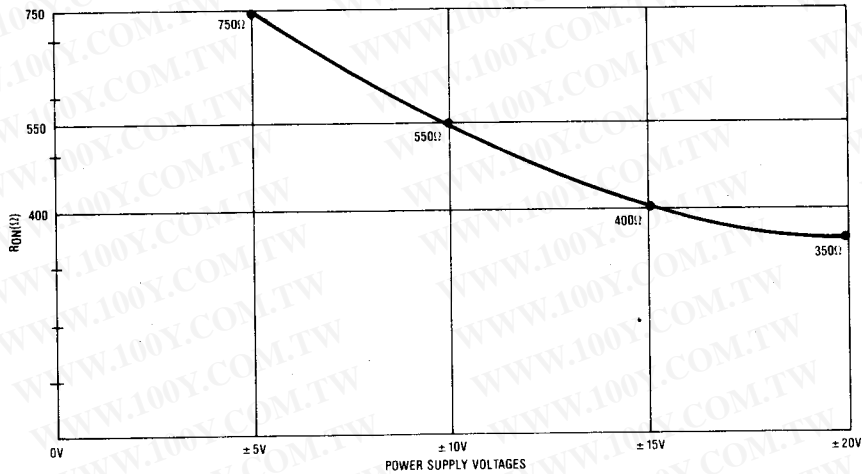
TEST CIRCUIT NO. 1
 ON RESISTANCE vs.
 INPUT SIGNAL LEVEL



V_{IN} vs. R_{ON}



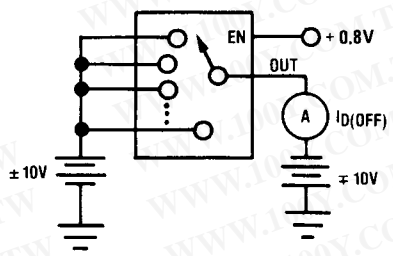
R_{ON} vs. POWER SUPPLY VOLTAGES
 INPUT = 0V



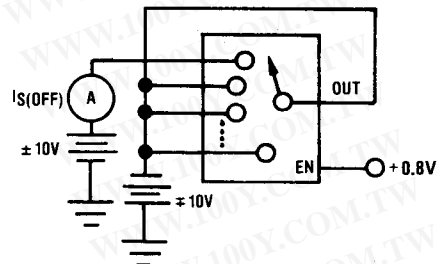
HI-508L TEST CIRCUITS

HI-508L/509L

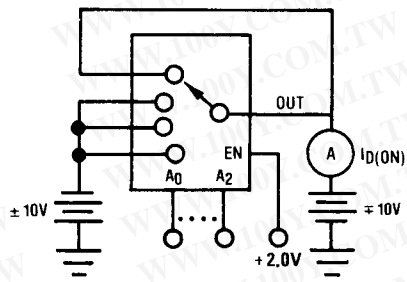
TEST CIRCUIT NO. 2*



TEST CIRCUIT NO. 3*



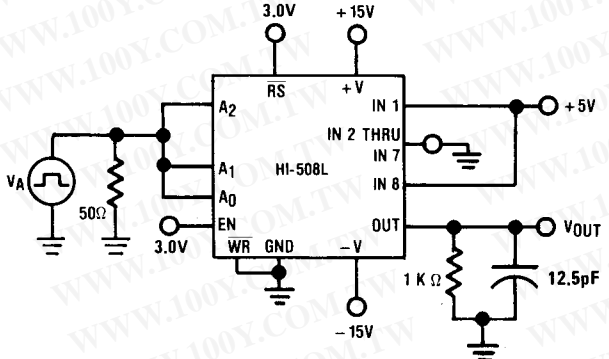
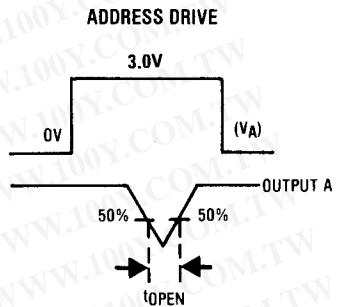
TEST CIRCUIT NO. 4*



*Two measurements per channel:
 +10V/-10V and -10V/+10V.
 (Two measurements per device for I_D(OFF)
 +10V/-10V and -10V/+10V.)

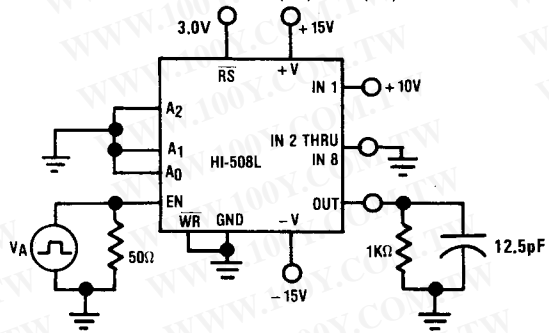
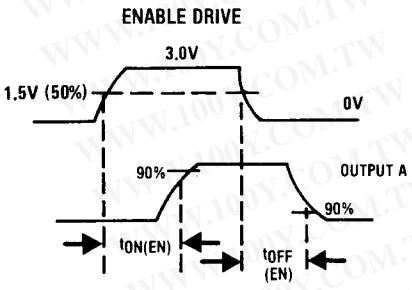
TEST CIRCUIT NO. 5

BREAK-BEFORE-MAKE DELAY (t_{OPEN})



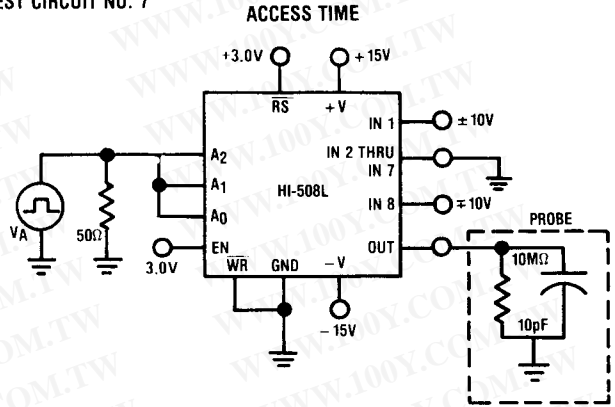
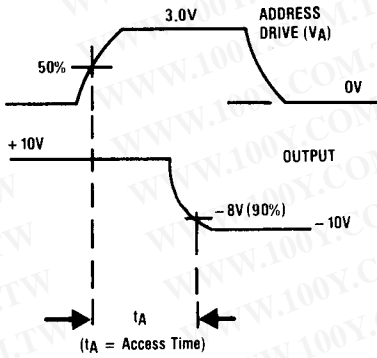
TEST CIRCUIT NO. 6

ENABLE DELAY (t_{ON}(EN), t_{OFF}(EN))

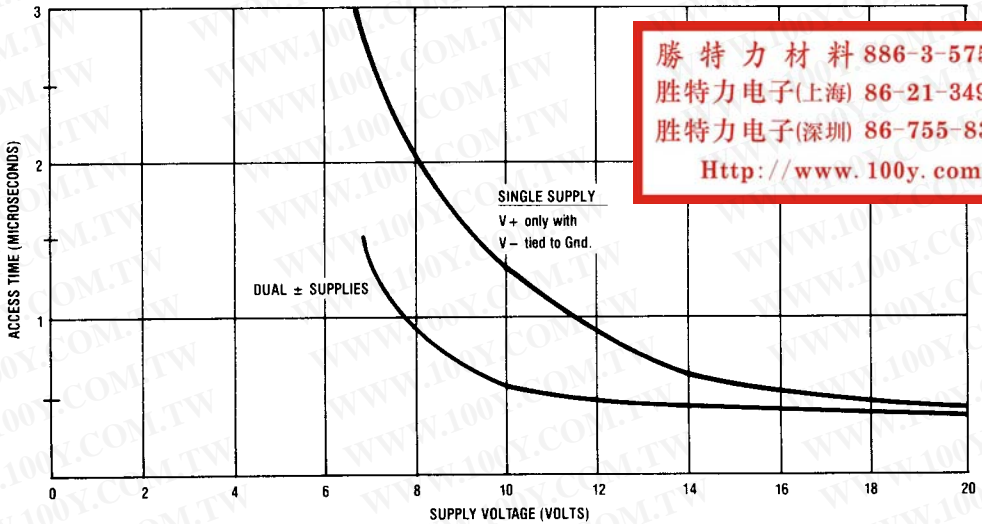


HI-508L TEST CIRCUITS

TEST CIRCUIT NO. 7

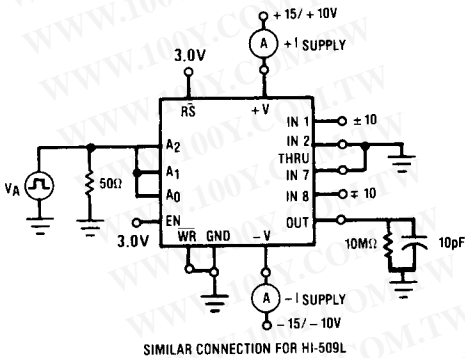


ACCESS TIME vs. SUPPLY VOLTAGE



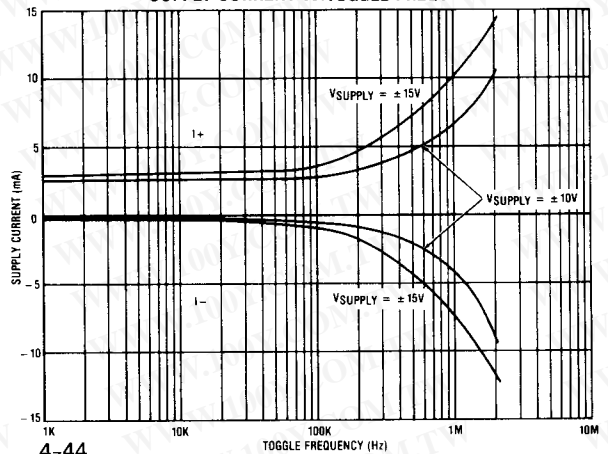
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TEST CIRCUIT NO. 8 SUPPLY CURRENTS vs. TOGGLE FREQUENCY

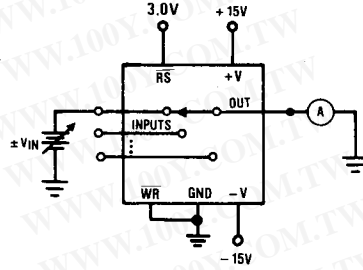
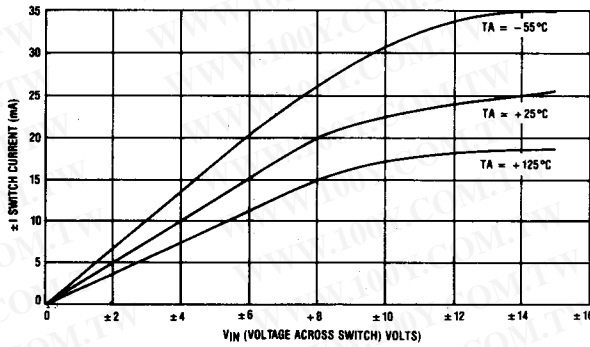


SIMILAR CONNECTION FOR HI-509L

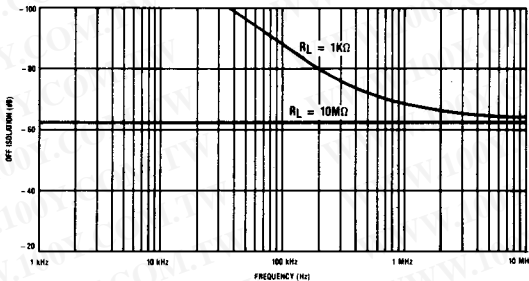
SUPPLY CURRENT vs. TOGGLE FREQUENCY



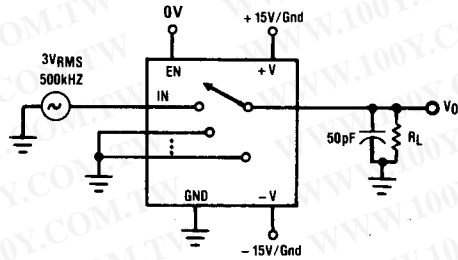
TEST CIRCUIT NO. 9
 ON CHANNEL CURRENT vs. INPUT VOLTAGE



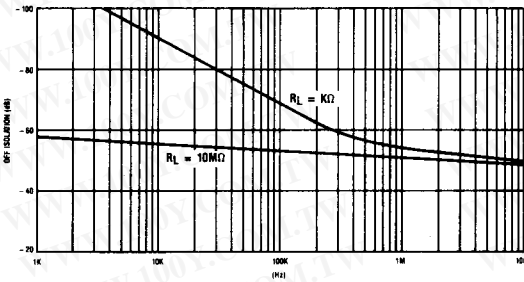
OFF ISOLATION vs. FREQUENCY POWER ON



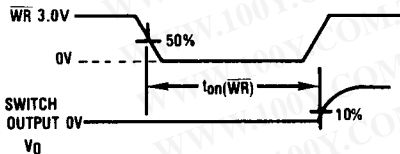
TEST CIRCUIT NO. 10
 OFF ISOLATION



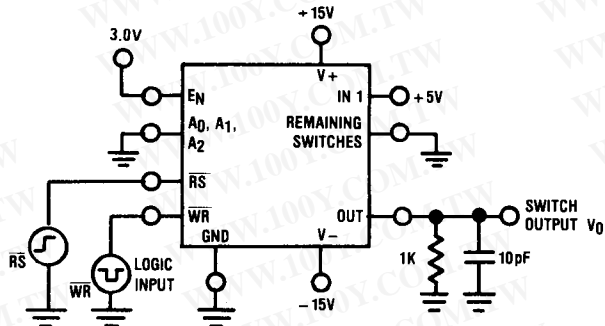
OFF ISOLATION vs. FREQUENCY (POWER OFF)



TEST CIRCUIT 11
 WRITE TURN-ON TIME $t_{ON}(WR)$

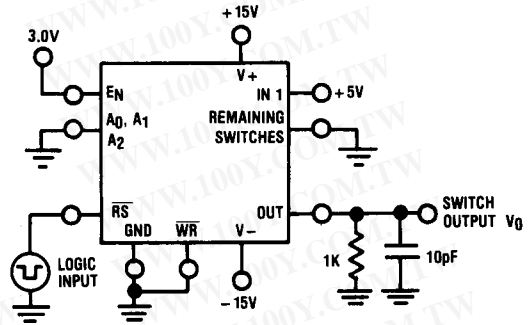
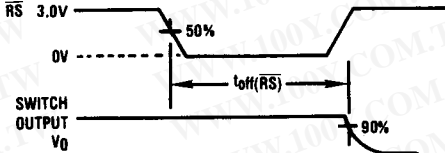


DEVICE MUST BE RESET PRIOR TO APPLYING WR PULSE

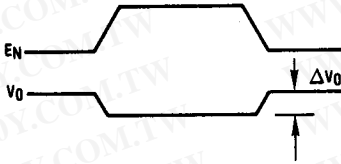


HI-508L TEST CIRCUITS

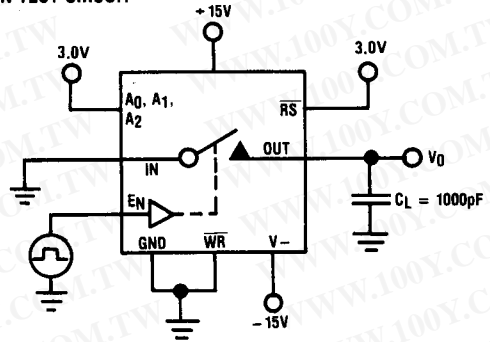
TEST CIRCUIT 12
RESET TURN-OFF TIME $t_{off}(RS)$



TEST CIRCUIT 13
CHARGE INJECTION TEST CIRCUIT



ΔV_0 IS THE MEASURED VOLTAGE ERROR DUE TO CHARGE INJECTION. THE ERROR VOLTAGE IN COULOMBS IS $Q = C_L \times \Delta V_0$.



DIE CHARACTERISTICS

Transistor Count	397
Die Size	124x114mils.
Thermal Impedance	
θ_{JA}	80°C/W
θ_{JC}	22°C/W
Tie Substrate to:	-V Supply
Process	CMOS-DI

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